
Tiny 1.5A, High-Speed Power MOSFET Driver

Features

- Passes Automotive AEC-Q100 Reliability Testing
- High Peak Output Current: 1.5A (typical)
- Wide Input Supply Voltage Operating Range:
 - 4.5V to 18V
- Low Shoot-Through/Cross-Conduction Current in Output Stage
- High Capacitive Load Drive Capability:
 - 470 pF in 13 ns (typical)
 - 1000 pF in 18 ns (typical)
- Short Delay Times: 44 ns (t_{D1}), 47 ns (MCP1415 t_{D2}), 54 ns (MCP1416 t_{D2}) (typical)
- Low Supply Current:
 - With Logic '1' Input - 0.65 mA (typical)
 - With Logic '0' Input - 0.1 mA (typical)
- Latch-Up Protected: Withstands 500 mA Reverse Current
- Logic Input Withstands Negative Swing up to 5V
- Space-Saving 5-Lead SOT-23 Package

Applications

- Switch Mode Power Supplies
- Pulse Transformer Drive
- Line Drivers
- Level Translator
- Motor and Solenoid Drive

General Description

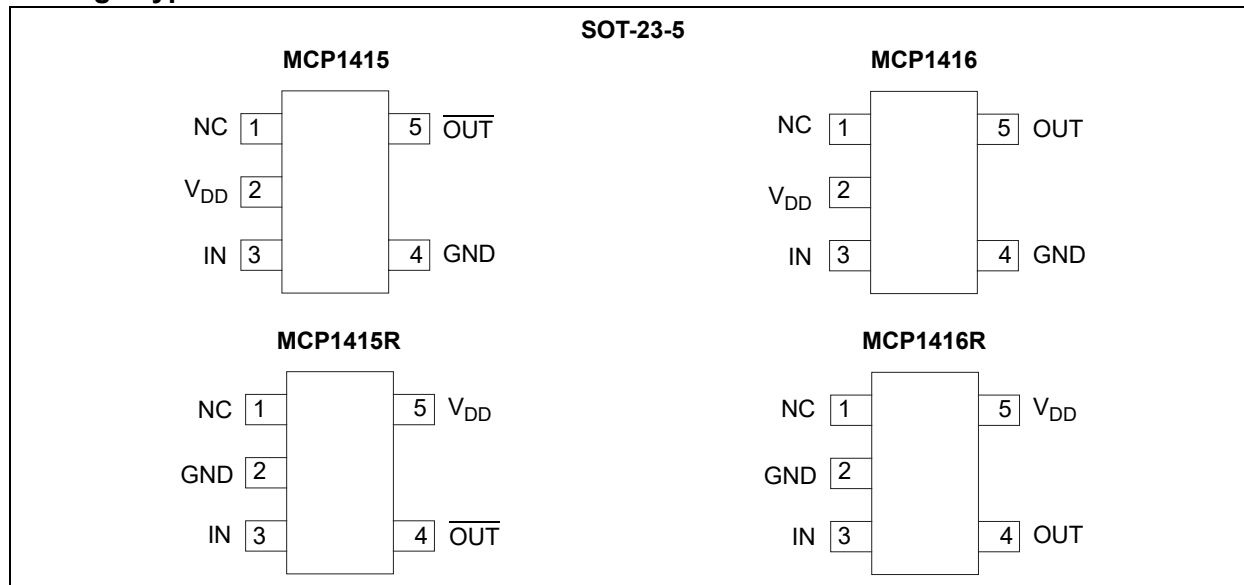
The MCP1415/16 devices are high-speed, dual MOSFET drivers that are capable of providing up to 1.5A of peak current while operating from a single 4.5V to 18V supply. The inverting or noninverting single channel output is directly controlled from either TTL or CMOS (3V to 18V) logic. These devices also feature low shoot-through current, matched rise and fall time, and short propagation delays which make them ideal for high switching frequency applications. They provide low enough impedances in both the 'On' and 'Off' states to ensure the intended state of the MOSFET is not affected, even by large transients.

These devices are highly latch-up resistant under any condition within their power and voltage ratings. They are not subject to damage when noise spiking (up to 5V, of either polarity) occurs on the Ground pin. They can accept up to 500 mA of reverse current being forced back into their outputs without damage or logic upset. All terminals are fully protected against electrostatic discharge (ESD) up to 2.0 kV (HBM) and 300V (MM).

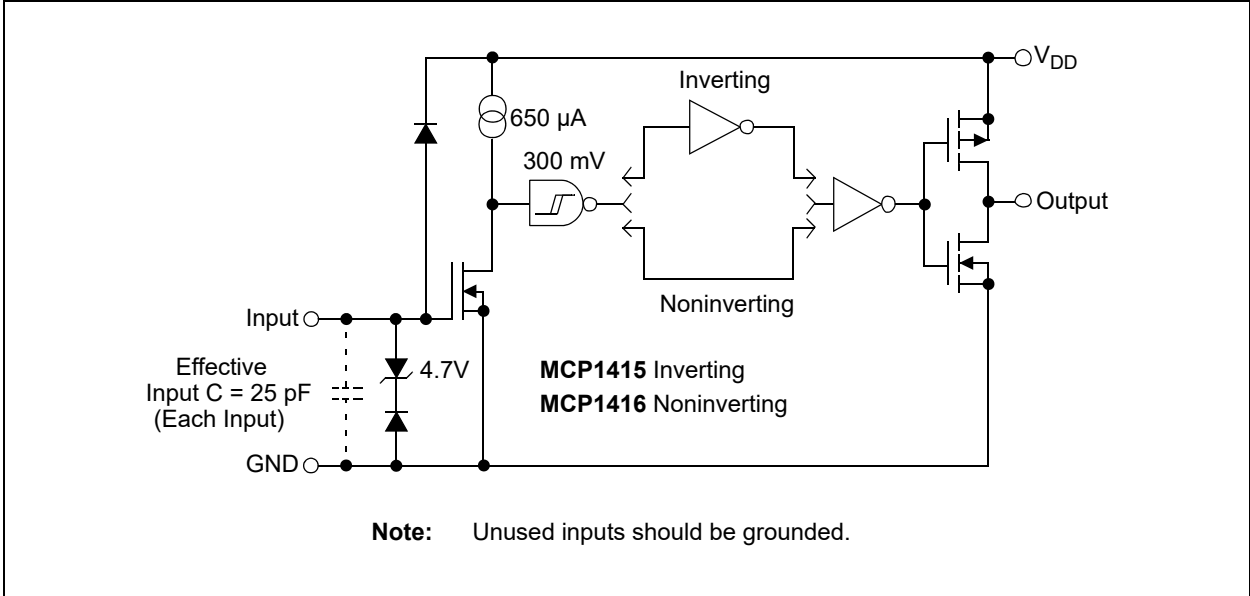
The MCP1415/16 is AEC-Q100 qualified for automotive applications.

MCP1415/16

Package Types



Functional Block Diagram



MCP1415/16

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

| | |
|--|-----------------------------------|
| V_{DD} , Supply Voltage | +20V |
| V_{IN} , Input Voltage | ($V_{DD} + 0.3V$) to (GND - 5V) |
| Package Power Dissipation ($T_A = 50^\circ C$) | |
| 5-Lead SOT-23 | 0.39W |
| ESD Protection on all Pins | 2.0 kV (HBM) |
| | 300V (MM) |

† **Notice:** Stresses above those listed under “Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

DC CHARACTERISTICS

| Electrical Specifications: Unless otherwise noted, $T_A = +25^\circ C$, with $4.5V \leq V_{DD} \leq 18V$ | | | | | | |
|---|-----------|------------------|------|----------------|----------|--|
| Parameters | Sym. | Min. | Typ. | Max. | Units | Conditions |
| Input | | | | | | |
| Logic '1' High Input Voltage | V_{IH} | 2.4 | 1.9 | — | V | |
| Logic '0' Low Input Voltage | V_{IL} | — | 1.6 | 0.8 | V | |
| Input Current | I_{IN} | -1 | — | +1 | μA | $0V \leq V_{IN} \leq V_{DD}$ |
| Input Voltage | V_{IN} | -5 | — | $V_{DD} + 0.3$ | V | |
| Output | | | | | | |
| High Output Voltage | V_{OH} | $V_{DD} - 0.025$ | — | — | V | DC Test |
| Low Output Voltage | V_{OL} | — | — | 0.025 | V | DC Test |
| Output Resistance, High | R_{OH} | — | 6 | 7.5 | Ω | $I_{OUT} = 10\text{ mA}$, $V_{DD} = 18V$ (Note 1) |
| Output Resistance, Low | R_{OL} | — | 4 | 5.5 | Ω | $I_{OUT} = 10\text{ mA}$, $V_{DD} = 18V$ (Note 1) |
| Peak Output Current | I_{PK} | — | 1.5 | — | A | $V_{DD} = 18V$ (Note 1) |
| Latch-Up Protection Withstand Reverse Current | I_{REV} | 0.5 | — | — | A | Duty cycle $\leq 2\%$, $t \leq 300\ \mu s$ (Note 1) |
| Switching Time (Note 1) | | | | | | |
| Rise Time | t_R | — | 18 | 25 | ns | $V_{DD} = 18V$, $C_L = 1000\text{ pF}$ Figure 4-1, Figure 4-2 (Note 1) |
| Fall Time | t_F | — | 21 | 28 | ns | $V_{DD} = 18V$, $C_L = 1000\text{ pF}$ Figure 4-1, Figure 4-2 (Note 1) |
| Delay Time | t_{D1} | — | 44 | 54 | ns | $V_{DD} = 18V$, $V_{IN} = 5V$ Figure 4-1, Figure 4-2 (Note 1) |
| MCP1415 Delay Time | t_{D2} | — | 47 | 57 | ns | $V_{DD} = 18V$, $V_{IN} = 5V$ Figure 4-1 (Note 1) |
| MCP1416 Delay Time | t_{D2} | — | 54 | 64 | ns | $V_{DD} = 18V$, $V_{IN} = 5V$ Figure 4-2 (Note 1) |
| Power Supply | | | | | | |
| Supply Voltage | V_{DD} | 4.5 | — | 18 | V | |
| Power Supply Current | I_S | — | 0.65 | 1.1 | mA | $V_{IN} = 3V$ |
| | I_S | — | 0.1 | 0.15 | mA | $V_{IN} = 0V$ |

Note 1: Tested during characterization, not production tested.

DC CHARACTERISTICS (OVER OPERATING TEMPERATURE RANGE) (Note 1)

| Electrical Specifications: Unless otherwise indicated, over the operating range with $4.5V \leq V_{DD} \leq 18V$. | | | | | | |
|--|----------|------------------|------|----------------|----------|--|
| Parameters | Sym. | Min. | Typ. | Max. | Units | Conditions |
| Input | | | | | | |
| Logic '1', High Input Voltage | V_{IH} | 2.4 | — | — | V | |
| Logic '0', Low Input Voltage | V_{IL} | — | — | 0.8 | V | |
| Input Current | I_{IN} | -10 | — | +10 | μA | $0V \leq V_{IN} \leq V_{DD}$ |
| Input Voltage | V_{IN} | -5 | — | $V_{DD} + 0.3$ | V | |
| Output | | | | | | |
| High Output Voltage | V_{OH} | $V_{DD} - 0.025$ | — | — | V | DC Test |
| Low Output Voltage | V_{OL} | — | — | 0.025 | V | DC Test |
| Output Resistance, High | R_{OH} | — | 8.5 | 9.5 | Ω | $I_{OUT} = 10 \text{ mA}$, $V_{DD} = 18V$ |
| Output Resistance, Low | R_{OL} | — | 6 | 7 | Ω | $I_{OUT} = 10 \text{ mA}$, $V_{DD} = 18V$ |
| Switching Time | | | | | | |
| Rise Time | t_R | — | 26 | 37 | ns | $V_{DD} = 18V$, $C_L = 1000 \text{ pF}$ Figure 4-1, Figure 4-2 |
| Fall Time | t_F | — | 29 | 40 | ns | $V_{DD} = 18V$, $C_L = 1000 \text{ pF}$ Figure 4-1, Figure 4-2 |
| Delay Time | t_{D1} | — | 60 | 70 | ns | $V_{DD} = 18V$, $V_{IN} = 5V$ Figure 4-1, Figure 4-2 |
| MCP1415 Delay Time | t_{D2} | — | 62 | 72 | ns | $V_{DD} = 18V$, $V_{IN} = 5V$ Figure 4-1 |
| MCP1416 Delay Time | t_{D2} | — | 72 | 82 | ns | $V_{DD} = 18V$, $V_{IN} = 5V$ Figure 4-2 |
| Power Supply | | | | | | |
| Supply Voltage | V_{DD} | 4.5 | — | 18 | V | |
| Power Supply Current | I_S | — | 0.75 | 1.5 | mA | $V_{IN} = 3.0V$ |
| | I_S | — | 0.15 | 0.25 | mA | $V_{IN} = 0V$ |

Note 1: Tested during characterization, not production tested.

TEMPERATURE CHARACTERISTICS

| Electrical Specifications: Unless otherwise noted, all parameters apply with $4.5V \leq V_{DD} \leq 18V$ | | | | | | |
|--|---------------|------|-------|------|---------------|----------|
| Parameter | Sym. | Min. | Typ. | Max. | Units | Comments |
| Temperature Ranges | | | | | | |
| Specified Temperature Range | T_A | -40 | — | +125 | $^{\circ}C$ | |
| Maximum Junction Temperature | T_J | — | — | +150 | $^{\circ}C$ | |
| Storage Temperature Range | T_A | -65 | — | +150 | $^{\circ}C$ | |
| Package Thermal Resistances | | | | | | |
| Thermal Resistance, 5-Lead SOT-23 | θ_{JA} | — | 220.7 | — | $^{\circ}C/W$ | |

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2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated, $T_A = +25^\circ\text{C}$ with $4.5\text{V} \leq V_{DD} \leq 18\text{V}$.

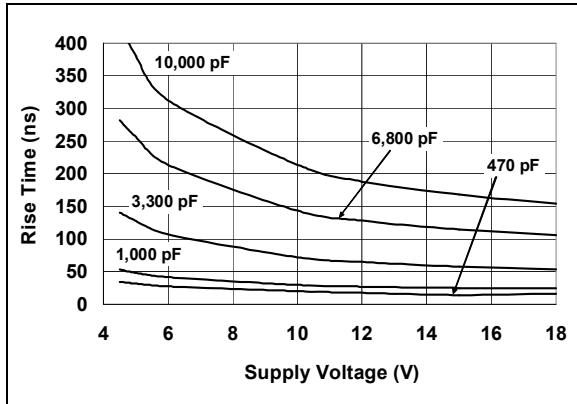


FIGURE 2-1: Rise Time vs. Supply Voltage.

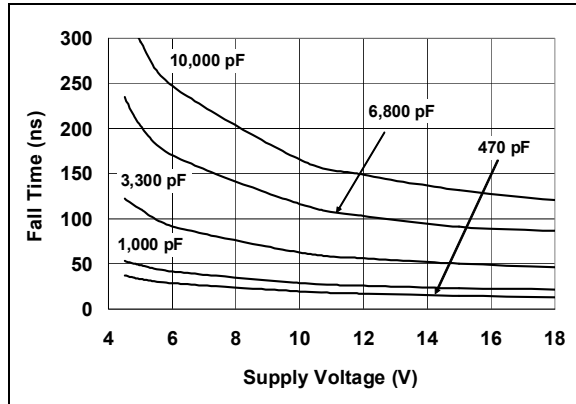


FIGURE 2-4: Fall Time vs. Supply Voltage.

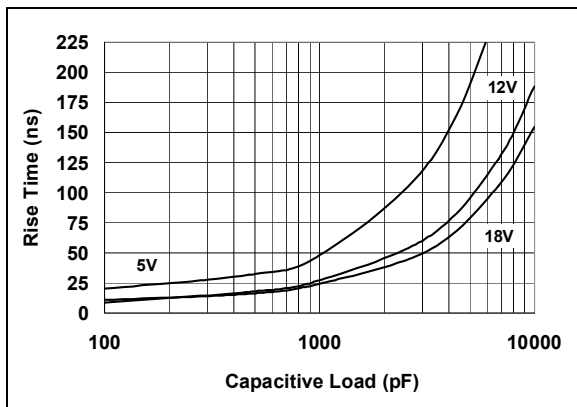


FIGURE 2-2: Rise Time vs. Capacitive Load.

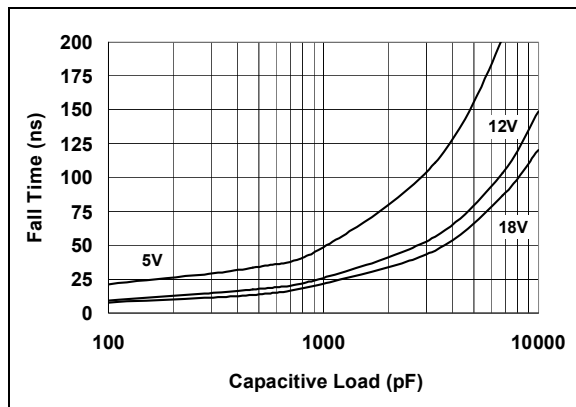


FIGURE 2-5: Fall Time vs. Capacitive Load.

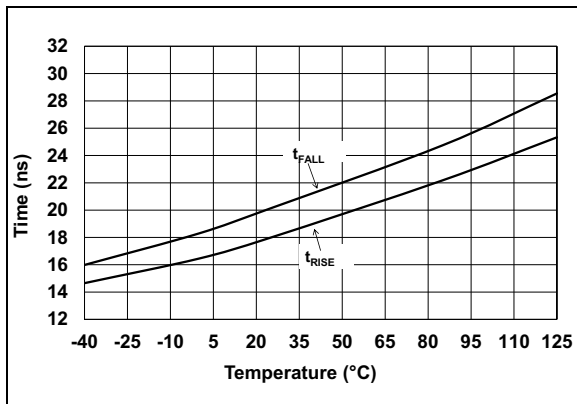


FIGURE 2-3: Rise and Fall Times vs. Temperature.

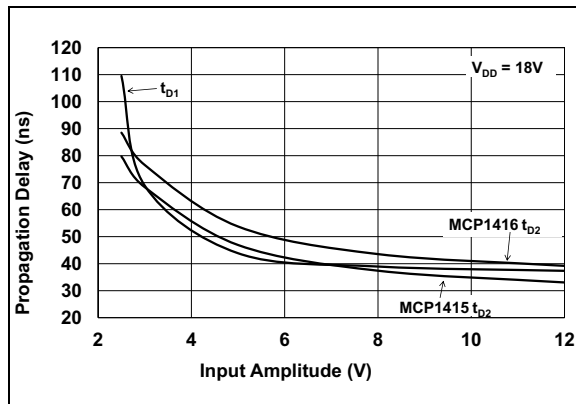


FIGURE 2-6: Propagation Delay Time vs. Input Amplitude.

Note: Unless otherwise indicated, $T_A = +25^\circ\text{C}$ with $4.5\text{V} \leq V_{DD} \leq 18\text{V}$.

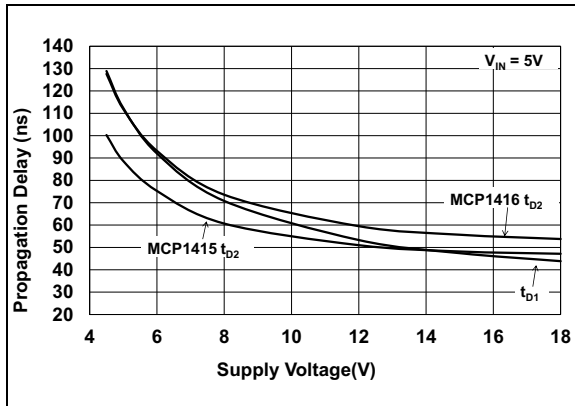


FIGURE 2-7: Propagation Delay Time vs. Supply Voltage.

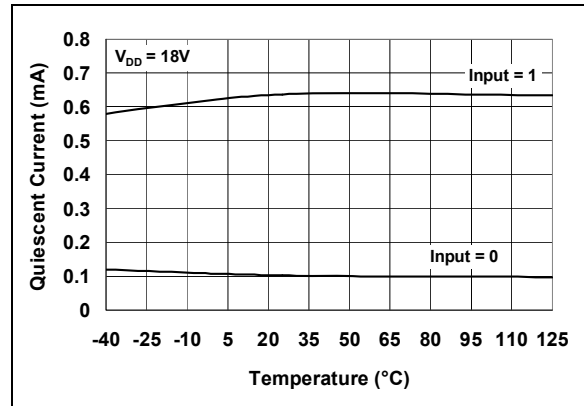


FIGURE 2-10: Quiescent Current vs. Temperature.

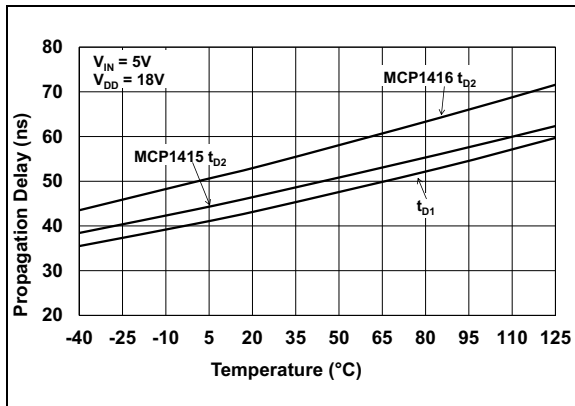


FIGURE 2-8: Propagation Delay Time vs. Temperature.

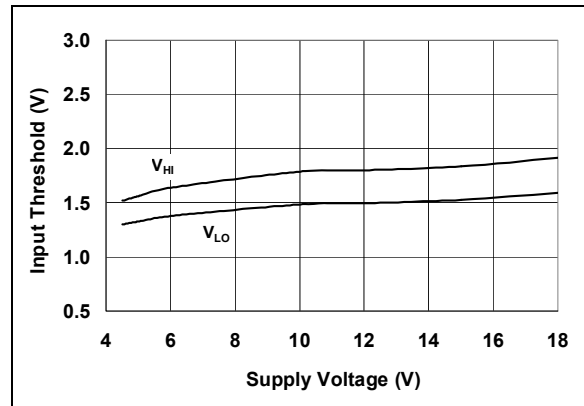


FIGURE 2-11: Input Threshold vs. Supply Voltage.

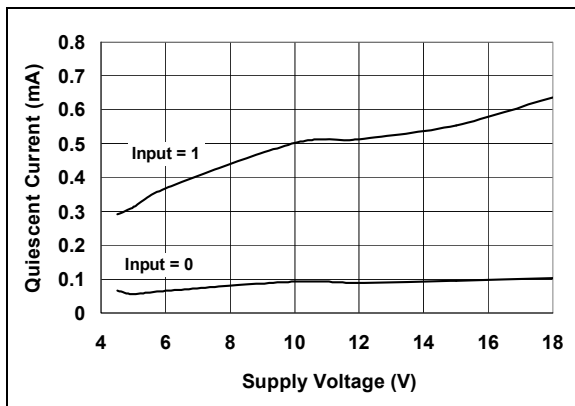


FIGURE 2-9: Quiescent Current vs. Supply Voltage.

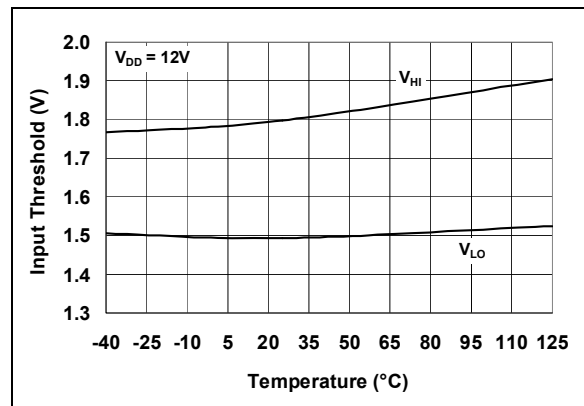


FIGURE 2-12: Input Threshold vs. Temperature.

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Note: Unless otherwise indicated, $T_A = +25^\circ\text{C}$ with $4.5\text{V} \leq V_{DD} \leq 18\text{V}$.

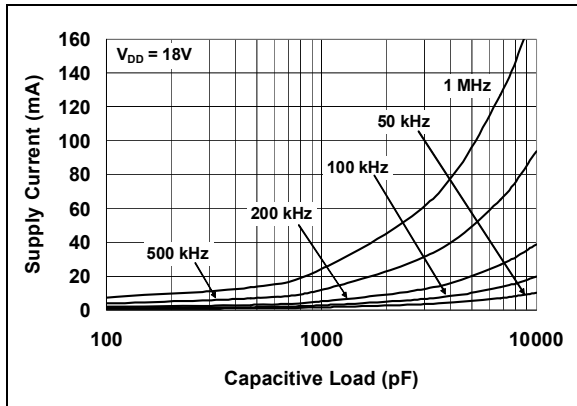


FIGURE 2-13: Supply Current vs. Capacitive Load.

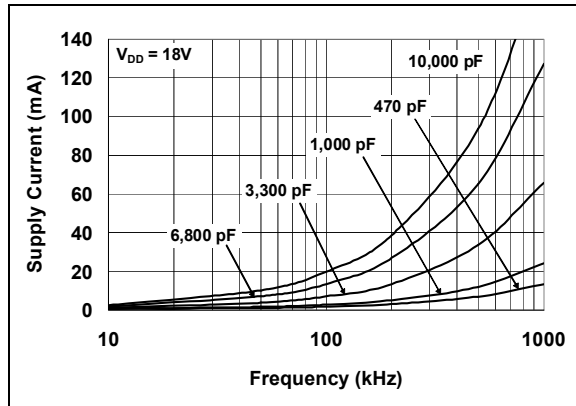


FIGURE 2-16: Supply Current vs. Frequency.

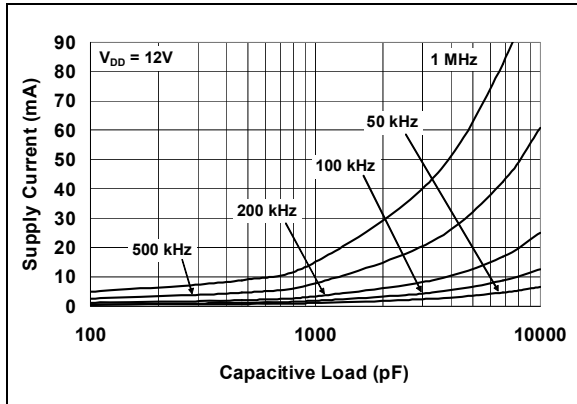


FIGURE 2-14: Supply Current vs. Capacitive Load.

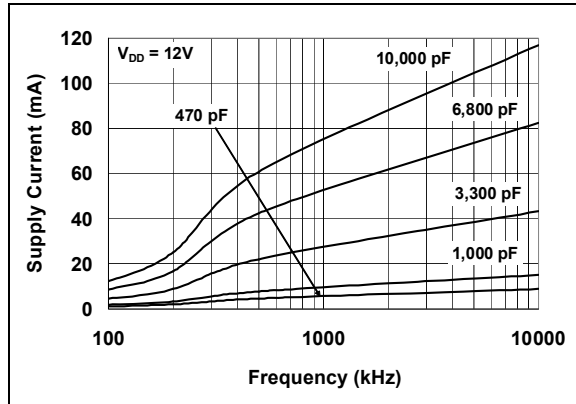


FIGURE 2-17: Supply Current vs. Frequency.

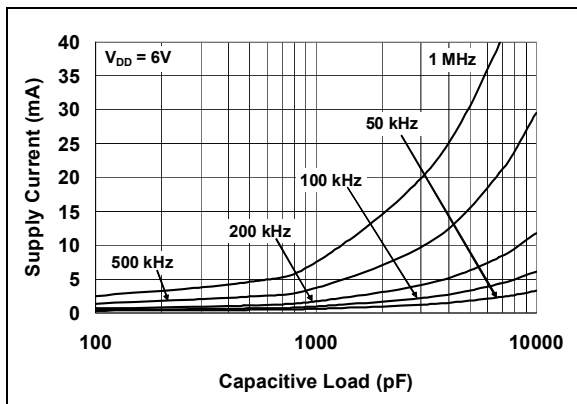


FIGURE 2-15: Supply Current vs. Capacitive Load.

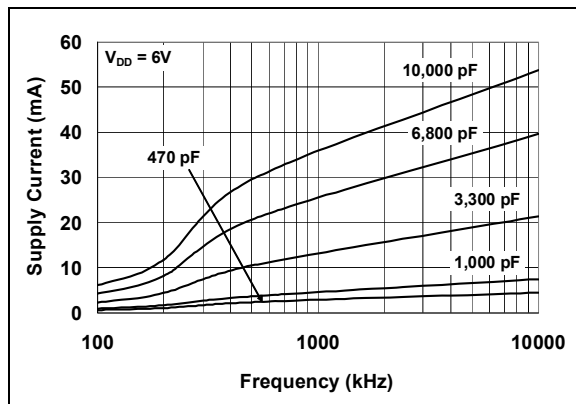


FIGURE 2-18: Supply Current vs. Frequency.

Note: Unless otherwise indicated, $T_A = +25^\circ\text{C}$ with $4.5\text{V} \leq V_{DD} \leq 18\text{V}$.

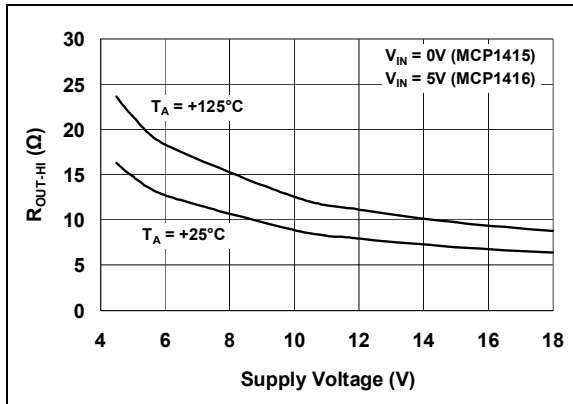


FIGURE 2-19: Output Resistance (Output High) vs. Supply Voltage.

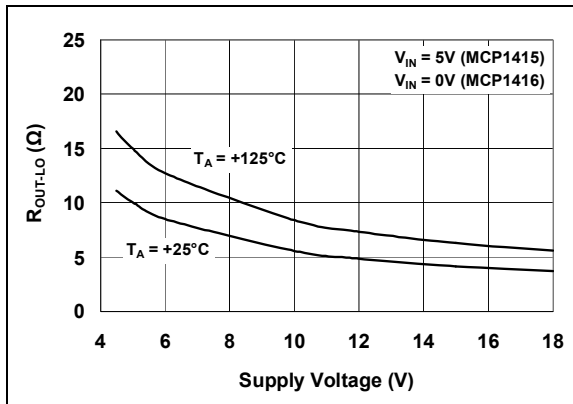


FIGURE 2-20: Output Resistance (Output Low) vs. Supply Voltage.

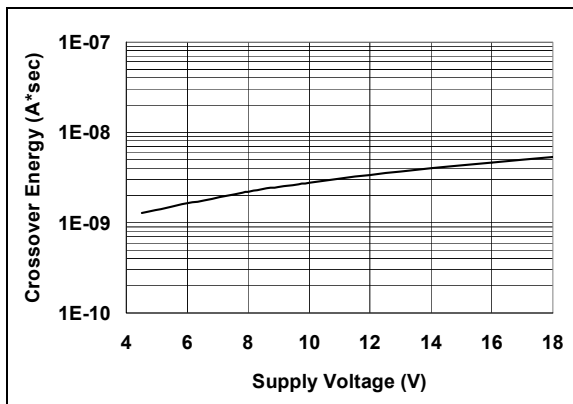


FIGURE 2-21: Crossover Energy vs. Supply Voltage.

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3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in [Table 3-1](#).

TABLE 3-1: PIN FUNCTION TABLE

| Pin No. | | Symbol | Description |
|------------|--------------|------------------------------------|---------------|
| MCP1415/16 | MCP1415R/16R | | |
| 1 | 1 | NC | No Connection |
| 2 | 5 | V_{DD} | Supply Input |
| 3 | 3 | IN | Control Input |
| 4 | 2 | GND | Ground |
| 5 | 4 | $\overline{\text{OUT}}/\text{OUT}$ | Output |

3.1 Supply Input (V_{DD})

V_{DD} is the bias supply input for the MOSFET driver and has a voltage range of 4.5V to 18V. This input must be decoupled to ground with a local capacitor. This bypass capacitor provides a localized low-impedance path for the peak currents that are provided to the load.

3.2 Control Input (IN)

The MOSFET driver input is a high-impedance, TTL/CMOS compatible input. The input also has hysteresis between the high and low input levels, allowing them to be driven from slow rising and falling signals and to provide noise immunity.

3.3 Ground (GND)

Ground is the device return pin. The ground pin should have a low-impedance connection to the bias supply source return. When the capacitive load is being discharged, high peak currents will flow out of the ground pin.

3.4 Output (OUT, $\overline{\text{OUT}}$)

The output is a CMOS push-pull output that is capable of sourcing and sinking 1.5A of peak current ($V_{DD} = 18V$). The low output impedance ensures the gate of the external MOSFET stays in the intended state even during large transients. This output also has a reverse current latch-up rating of 500 mA.

4.0 APPLICATION INFORMATION

4.1 General Information

MOSFET drivers are high-speed, high-current devices which are intended to source/sink high peak currents that are used to charge/discharge the gate capacitance of external MOSFETs or Insulated-Gate Bipolar Transistors (IGBTs). In high frequency switching power supplies, the Pulse-Width Modulation (PWM) controller may not have the drive capability to directly drive the power MOSFET. A MOSFET driver such as the MCP1415/16 family can be used to provide additional source/sink current capability.

4.2 MOSFET Driver Timing

The ability of a MOSFET driver to transition from a fully-off state to a fully-on state is characterized by the driver's rise time (t_R), fall time (t_F) and propagation delays (t_{D1} and t_{D2}). Figure 4-1 and Figure 4-2 show the test circuit and timing waveform used to verify the MCP1415/16 timing.

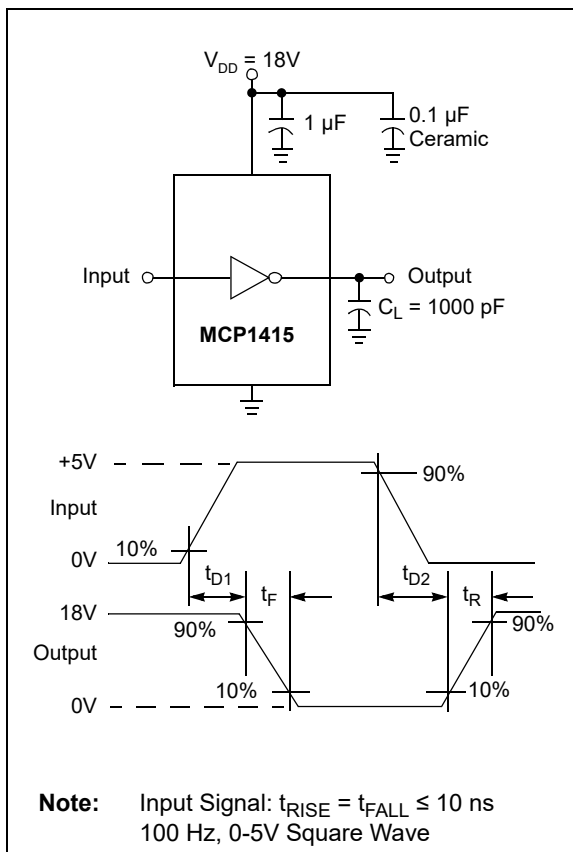


FIGURE 4-1: Inverting Driver Timing Waveform.

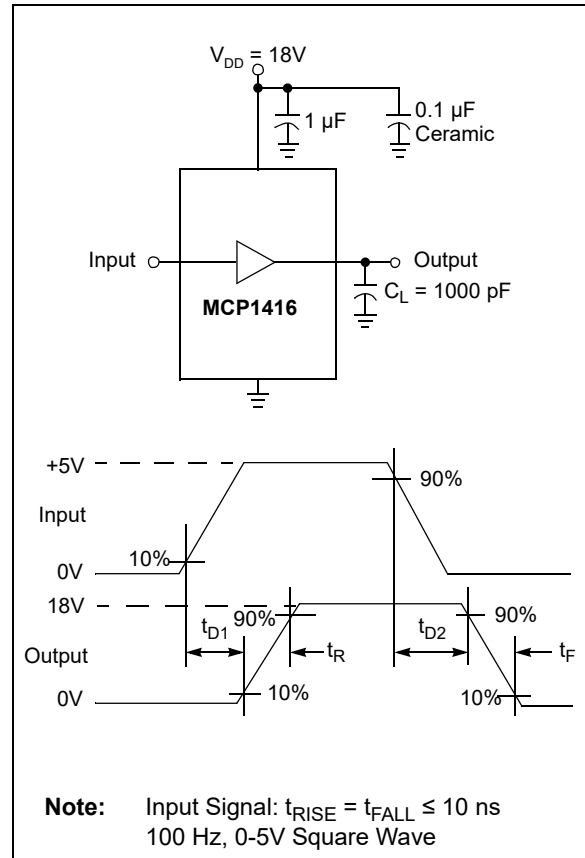


FIGURE 4-2: Noninverting Driver Timing Waveform.

4.3 Decoupling Capacitors

Careful layout and decoupling capacitors are required when using power MOSFET drivers. Large current is required to charge and discharge capacitive loads quickly. For example, approximately 720 mA are needed to charge a 1000 pF load with 18V in 25 ns.

To operate the MOSFET driver over a wide frequency range with low supply impedance, it is recommended to place a ceramic and a low ESR film capacitor in parallel between the driver V_{DD} and GND. A 1.0 μF low ESR film capacitor and a 0.1 μF ceramic capacitor placed between pins 2 and 4 are required for reliable operation. These capacitors should be placed close to the driver to minimize circuit board parasitics and provide a local source for the required current.

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4.4 Power Dissipation

The total internal power dissipation in a MOSFET driver is the summation of three separate power dissipation elements.

EQUATION 4-1:

$$P_T = P_L + P_Q + P_{CC}$$

Where:

- P_T = Total power dissipation
- P_L = Load power dissipation
- P_Q = Quiescent power dissipation
- P_{CC} = Operating power dissipation

4.4.1 CAPACITIVE LOAD DISSIPATION

The power dissipation caused by a capacitive load is a direct function of the frequency, total capacitive load and supply voltage. The power lost in the MOSFET driver for a complete charging and discharging cycle of a MOSFET is shown in Equation 4-2.

EQUATION 4-2:

$$P_L = f \times C_T \times V_{DD}^2$$

Where:

- f = Switching frequency
- C_T = Total load capacitance
- V_{DD} = MOSFET driver supply voltage

4.4.2 QUIESCENT POWER DISSIPATION

The power dissipation associated with the quiescent current draw depends on the state of the input pin. The MCP1415/16 devices have a quiescent current draw of 0.65 mA (typical) when the input is high and of 0.1 mA (typical) when the input is low. The quiescent power dissipation is shown in Equation 4-3.

EQUATION 4-3:

$$P_Q = (I_{QH} \times D + I_{QL} \times (1 - D)) \times V_{DD}$$

Where:

- I_{QH} = Quiescent current in the High state
- D = Duty cycle
- I_{QL} = Quiescent current in the Low state
- V_{DD} = MOSFET driver supply voltage

4.4.3 OPERATING POWER DISSIPATION

The operating power dissipation occurs each time the MOSFET driver output transitions because, for a very short period of time, both MOSFETs in the output stage are on simultaneously. This cross-conduction current leads to a power dissipation described in Equation 4-4.

EQUATION 4-4:

$$P_{CC} = CC \times f \times V_{DD}$$

Where:

- CC = Cross-Conduction constant (A*sec)
- f = Switching frequency
- V_{DD} = MOSFET driver supply voltage

4.5 PCB Layout Considerations

Proper PCB layout is important in high-current, fast switching circuits to provide proper device operation and robustness of design. Improper component placement may cause errant switching, excessive voltage ringing or circuit latch-up. PCB trace loop area and inductance must be minimized. This is accomplished by placing the MOSFET driver directly at the load and placing the bypass capacitor directly at the MOSFET driver (see Figure 4-3). Locating ground planes or ground return traces directly beneath the driver output signal reduces trace inductance. A ground plane also helps as a radiated noise shield and it provides some heat sinking for power dissipated within the device (see Figure 4-4).

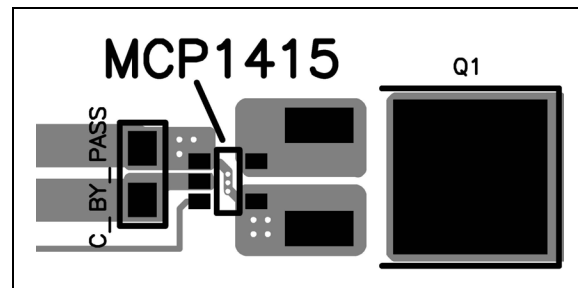


FIGURE 4-3: Recommended PCB Layout (TOP).

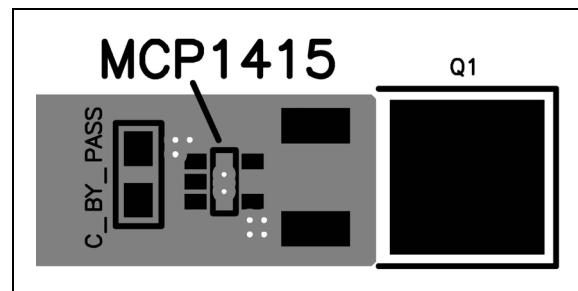
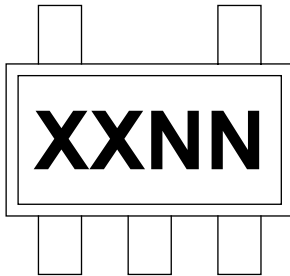


FIGURE 4-4: Recommended PCB Layout (BOTTOM).

5.0 PACKAGING INFORMATION

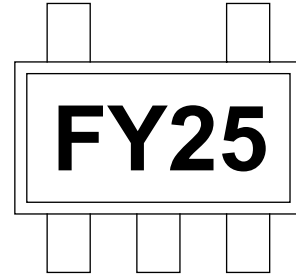
5.1 Package Marking Information

5-Lead SOT-23



| Standard Markings for SOT-23 | |
|------------------------------|------|
| Part Number | Code |
| MCP1415T-E/OT | FYNN |
| MCP1415RT-E/OT | F7NN |
| MCP1415T-E/OTVAO | FYNN |
| MCP1416T-E/OT | FZNN |
| MCP1416T-E/OTVAO | FZNN |
| MCP1416RT-E/OT | F8NN |
| MCP1416RT-E/OTVAO | F8NN |

Example



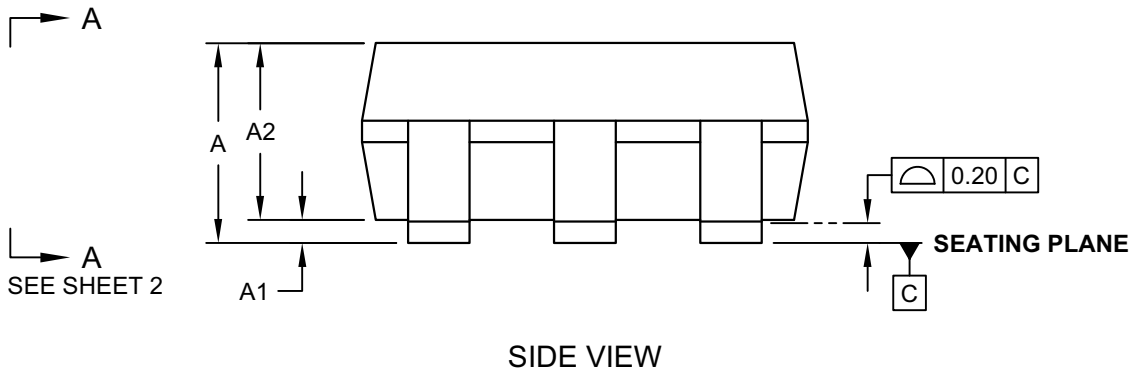
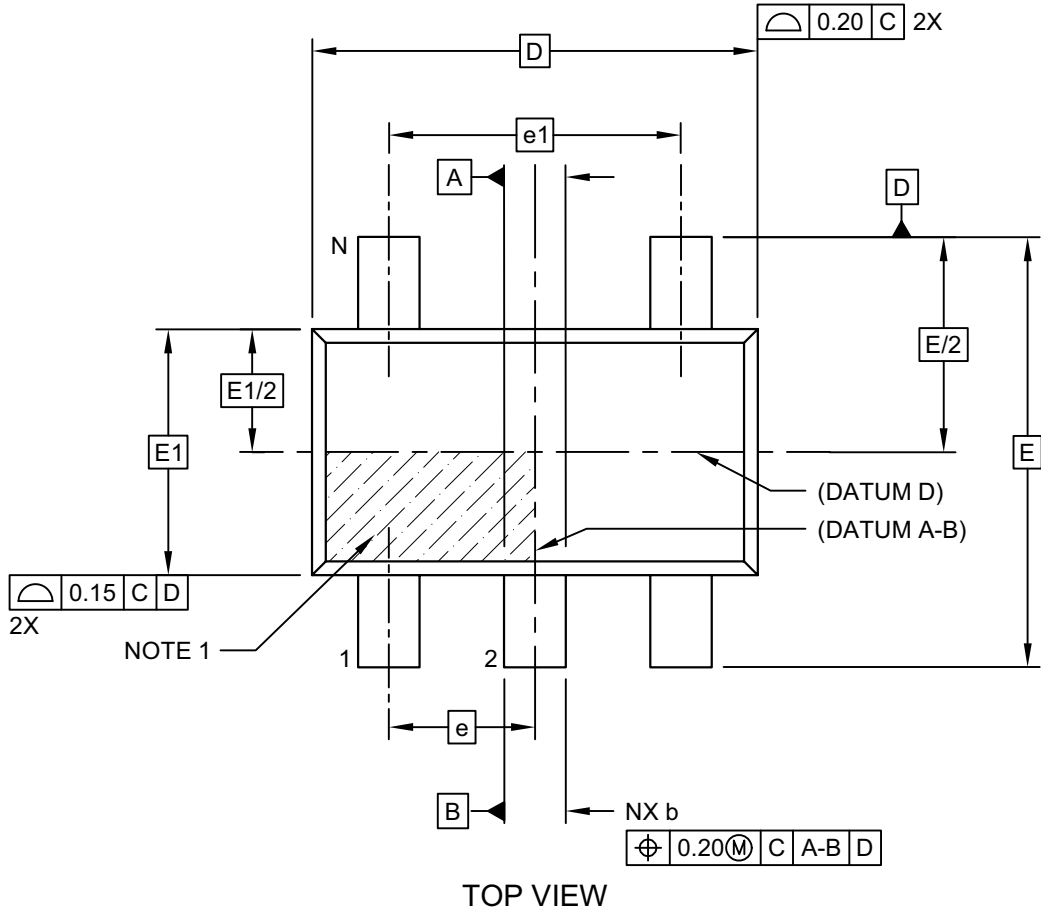
| | | |
|----------------|--------|--|
| Legend: | XX...X | Customer-specific information |
| | Y | Year code (last digit of calendar year) |
| | YY | Year code (last 2 digits of calendar year) |
| | WW | Week code (week of January 1 is week '01') |
| | NNN | Alphanumeric traceability code |
| | (e3) | Pb-free JEDEC® designator for Matte Tin (Sn) |
| | * | This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package. |

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

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5-Lead Plastic Small Outline Transistor (OT) [SOT23]

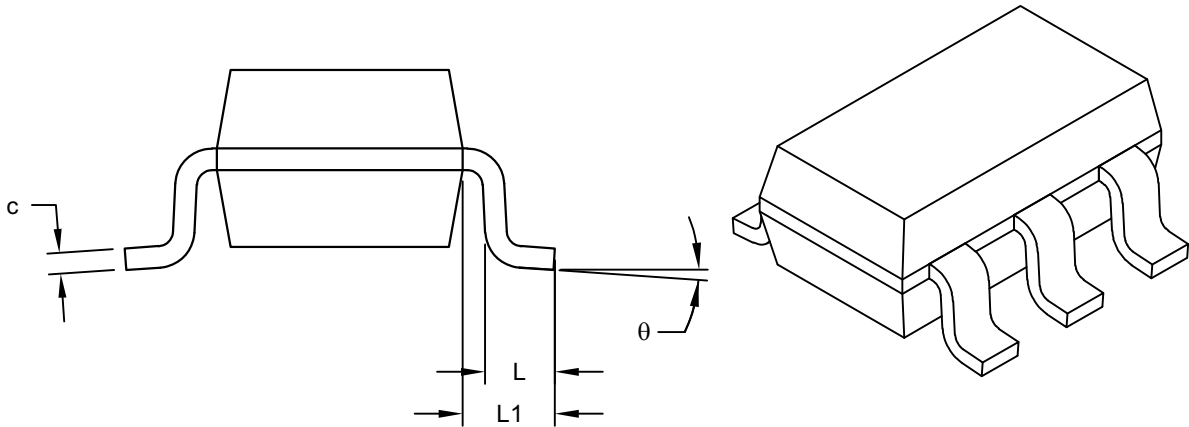
Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packageing>



Microchip Technology Drawing C04-091-OT Rev G Sheet 1 of 2

5-Lead Plastic Small Outline Transistor (OT) [SOT23]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



VIEW A-A
SHEET 1

| Dimension Limits | Units | MILLIMETERS | | |
|--------------------------|--------|-------------|-----|------|
| | | MIN | NOM | MAX |
| Number of Pins | N | 5 | | |
| Pitch | e | 0.95 BSC | | |
| Outside lead pitch | e1 | 1.90 BSC | | |
| Overall Height | A | 0.90 | - | 1.45 |
| Molded Package Thickness | A2 | 0.89 | - | 1.30 |
| Standoff | A1 | - | - | 0.15 |
| Overall Width | E | 2.80 BSC | | |
| Molded Package Width | E1 | 1.60 BSC | | |
| Overall Length | D | 2.90 BSC | | |
| Foot Length | L | 0.30 | - | 0.60 |
| Footprint | L1 | 0.60 REF | | |
| Foot Angle | ϕ | 0° | - | 10° |
| Lead Thickness | c | 0.08 | - | 0.26 |
| Lead Width | b | 0.20 | - | 0.51 |

Notes:

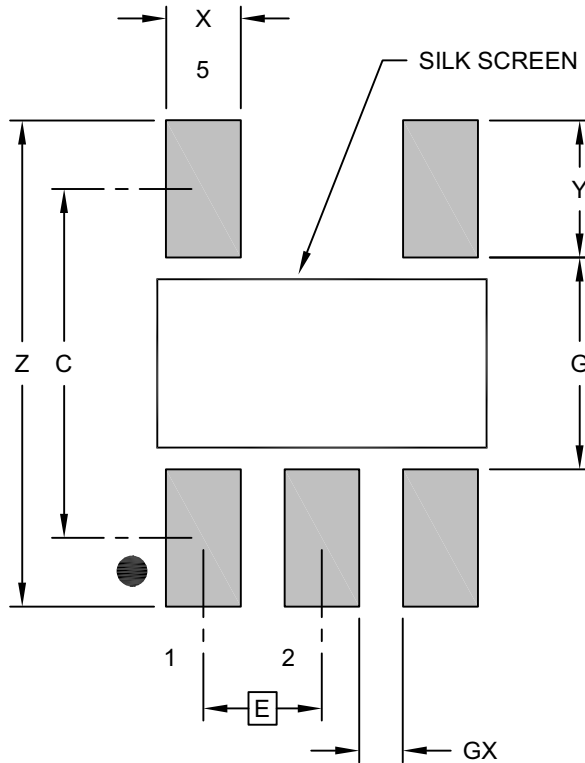
- Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.25mm per side.
- Dimensioning and tolerancing per ASME Y14.5M
 BSC: Basic Dimension. Theoretically exact value shown without tolerances.
 REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-091-OT Rev G Sheet 2 of 2

MCP1415/16

5-Lead Plastic Small Outline Transistor (OT) [SOT23]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



RECOMMENDED LAND PATTERN

| Dimension Limits | Units | MILLIMETERS | | |
|-------------------------|-------|-------------|------|------|
| | | MIN | NOM | MAX |
| Contact Pitch | E | 0.95 BSC | | |
| Contact Pad Spacing | C | | 2.80 | |
| Contact Pad Width (X5) | X | | | 0.60 |
| Contact Pad Length (X5) | Y | | | 1.10 |
| Distance Between Pads | G | 1.70 | | |
| Distance Between Pads | GX | 0.35 | | |
| Overall Width | Z | | | 3.90 |

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2091-OT Rev G

APPENDIX A: REVISION HISTORY

Revision H (November 2022)

- Added information about the Automotive Qualification status of the device in [Section “Features”](#).
- Updated package marking and drawings in [Section 5.0 “Packaging Information”](#).
- Updated [Section “Product Identification System”](#), with Automotive Qualified devices.
- Minor text and format changes throughout.

Revision G (June 2016)

The following is the list of modifications:

1. Updated [Features](#).
2. Updated [Section “DC Characteristics”](#).
3. Updated [Section “DC Characteristics \(Over Operating Temperature Range\) \(Note 1\)”](#).
4. Updated [Figure 2-3](#), [Figure 2-6](#), [Figure 2-7](#) and [Figure 2-8](#).
5. Updated [Figure 4-1](#) and [Figure 4-2](#).
6. Minor typographical corrections.

Revision F (July 2014)

The following is the list of modifications:

1. Fixed a typographical error for the electrostatic discharge (ESD) value in [Absolute Maximum Ratings †](#).
2. Minor grammatical and editorial corrections.

Revision E (May 2012)

The following is the list of modifications:

1. Updated the Electrostatic Discharge (ESD) value.

Revision D (December 2010)

The following is the list of modifications:

1. Updated [Figure 2-19](#) and [Figure 2-20](#).
2. Updated the package outline drawings.

Revision C (December 2008)

The following is the list of modifications:

Added the MCP1415R/16R devices throughout the document.

Revision B (June 2008)

The following is the list of modifications:

1. [Section “DC Characteristics”](#), Switching Time, Rise Time: changed from 13 to 20.
2. [Section “DC Characteristics”](#), Switching Time, Fall Time: changed from 13 to 20.
3. [Section “DC Characteristics \(Over Operating Temperature Range\) \(Note 1\)”](#) (Over Operating Temperature Range), Switching Time, Rise Time: changed maximum from 35 to 40.
4. [Section “DC Characteristics \(Over Operating Temperature Range\) \(Note 1\)”](#) (Over Operating Temperature Range), Switching Time, Rise Time: changed typical from 25 to 30.
5. [Section “DC Characteristics \(Over Operating Temperature Range\) \(Note 1\)”](#) (Over Operating Temperature Range), Switching Time, Fall Time: changed maximum from 35 to 40.
6. [Section “DC Characteristics \(Over Operating Temperature Range\) \(Note 1\)”](#) (Over Operating Temperature Range), Switching Time, Fall Time: changed typical from 25 to 30.

Revision A (June 2008)

Original release of this document.

MCP1415/16

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

| <u>PART NO.</u> | <u>-X</u> | <u>XX</u> | <u>XXX</u> | Examples: |
|--|-------------------|-----------|---------------|---|
| Device | Temperature Range | Package | Qualification | |
| Device: MCP1415T: 1.5A MOSFET Driver, Inverting, (Tape and Reel) MCP1415RT: 1.5A MOSFET Driver, Inverting, (Tape and Reel) MCP1416T: 1.5A MOSFET Driver, Noninverting (Tape and Reel) MCP1416RT: 1.5A MOSFET Driver, Noninverting, (Tape and Reel) | | | | a) MCP1415T-E/OT: 1.5A Inverting, MOSFET Driver, 5-Lead SOT-23 package |
| Temperature Range: E = -40°C to +125°C | | | | b) MCP1415RT-E/OT: 1.5A Inverting, MOSFET Driver, 5-Lead SOT-23 package |
| Package: * OT = Plastic Thin Small Outline Transistor (OT), 5-Lead * All package offerings are Pb Free (Lead Free). | | | | c) MCP1415T-E/OTVAO: 1.5A Inverting, MOSFET Driver, 5-Lead SOT-23 package, Automotive Qualified |
| Qualification: <Blank>= Standard Part VAO = Automotive AEC-Q100 Qualified | | | | d) MCP1416T-E/OT: 1.5A Noninverting, MOSFET Driver, 5-Lead SOT-23 package |
| | | | | e) MCP1416RT-E/OT: 1.5A Noninverting, MOSFET Driver, 5-Lead SOT-23 package |
| | | | | f) MCP1416T-E/OTVAO: 1.5A Noninverting, MOSFET Driver, 5-Lead SOT-23 package, Automotive Qualified |
| | | | | g) MCP1416RT-E/OTVAO: 1.5A Noninverting, MOSFET Driver, 5-Lead SOT-23 package, Automotive Qualified |

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